

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|-----------------------------------------------------------|-----------------|----------------------------------|-----------------|--------------|------|
| Drain-Source Voltage | | | V_{DSS} | -12 | V |
| Gate-Source Voltage | | | V_{GSS} | ±8 | V |
| Continuous Drain Current V 4 5 V (Note 6) | Steady State | $T_A = +25$ °C $T_A = +70$ °C | | -5.5 -4.3 | А |
| Continuous Drain Current V _{GS} = -4.5V (Note 6) | t<5s | $T_A = +25$ °C $T_A = +70$ °C | ID | -6.5 -5.1 | А |
| Maximum Continuous Body Diode Forward Current (Note 6) | | | Is | -2.2 | Α |
| Pulsed Drain Current (10µs pulse, duty cycle = 1%) | | | I _{DM} | -25 | A |

Thermal Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | | |
|--------------------------------------------------|------------------------|---------------------|-------------|------|--|
| Dawer Dissipation (Note 5) | T _A = +25°C | D | 0.7 | W | |
| Power Dissipation (Note 5) | $T_A = +70$ °C | P_{D} | 0.4 | VV | |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady state | D | 193 | °C/W | |
| Thermal Resistance, Junction to Ambient (Note 3) | t<5s | $R_{\theta JA}$ | 135 | | |
| Power Dissipation (Note 6) | $T_A = +25$ °C | D- | 1.7 | W | |
| | $T_A = +70^{\circ}C$ | P_{D} | 1.1 | | |
| Thermal Resistance, Junction to Ambient (Note 6) | Steady state | D | 73 | °C/W | |
| mermai Resistance, Junction to Ambient (Note o) | t<5s | $R_{\theta JA}$ | 52 | | |
| Thermal Resistance, Junction to Case (Notes 6) | Steady state | $R_{\theta JC}$ | 17 | | |
| Operating and Storage Temperature Range | | T_{J} , T_{STG} | -55 to +150 | °C | |

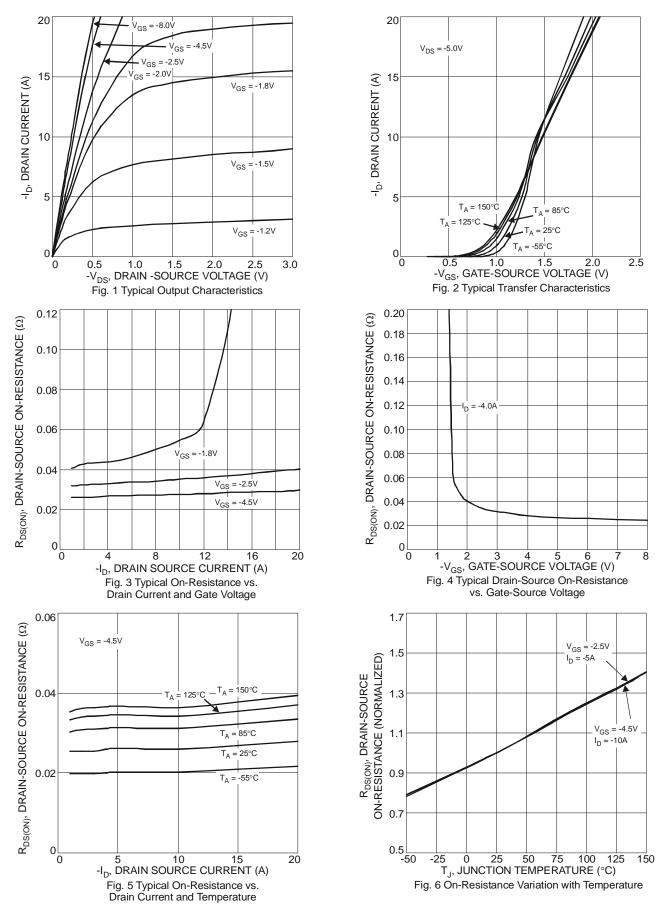
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|-------------------------------------------------------|----------------------|------|-------|------|------|------------------------------------------------------------------------|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -12 | - | - | V | $V_{GS} = 0V, I_D = -250\mu A$ | |
| Zero Gate Voltage Drain Current T _J = 25°C | I _{DSS} | - | - | -1.0 | μΑ | $V_{DS} = -12V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | - | - | ±10 | μΑ | $V_{GS} = \pm 8V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | -0.3 | -0.55 | -1.0 | V | $V_{DS} = V_{GS}, I_{D} = -250 \mu A$ | |
| | | - | 26 | 32 | mΩ | $V_{GS} = -4.5V$, $I_{D} = -4.0A$ | |
| Static Drain-Source On-Resistance | R _{DS (ON)} | | 31 | 45 | | $V_{GS} = -2.5V$, $I_D = -3.5A$ | |
| | | | 51 | 75 | | $V_{GS} = -1.8V$, $I_{D} = -2.7A$ | |
| Forward Transfer Admittance | Y _{fs} | - | 12 | - | S | $V_{DS} = -5V, I_{D} = -4A$ | |
| Diode Forward Voltage | V_{SD} | - | -0.6 | - | V | $V_{GS} = 0V, I_{S} = -1A$ | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | | |
| Input Capacitance | C _{iss} | - | 1291 | - | pF | $V_{DS} = -10V, V_{GS} = 0V$ f = 1.0MHz | |
| Output Capacitance | Coss | - | 266 | - | pF | | |
| Reverse Transfer Capacitance | C _{rss} | - | 242 | - | pF | | |
| Gate Resistnace | Rg | - | 13 | - | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$ | |
| SWITCHING CHARACTERISTICS (Note 8) | | | | | | | |
| Total Gate Charge (V _{GS} = -8V) | Qg | - | 23.7 | - | nC | V _{DS} = -10V, I _D = -4A | |
| Total Gate Charge (V _{GS} = -4.5V) | Qg | - | 14.7 | | nC | | |
| Gate-Source Charge | Q _{gs} | - | 1.8 | - | nC | | |
| Gate-Drain Charge | Q _{gd} | - | 4.6 | - | nC | | |
| Turn-On Delay Time | t _{D(on)} | - | 14 | - | ns | | |
| Turn-On Rise Time | t _r | - | 22 | - | ns | $V_{DS} = -10V, V_{GS} = -4.5V,$ $R_L = 2.5\Omega, R_G = 3.0\Omega$ | |
| Turn-Off Delay Time | t _{D(off)} | - | 74 | - | ns | | |
| Turn-Off Fall Time | t _f | - | 75 | - | ns | | |

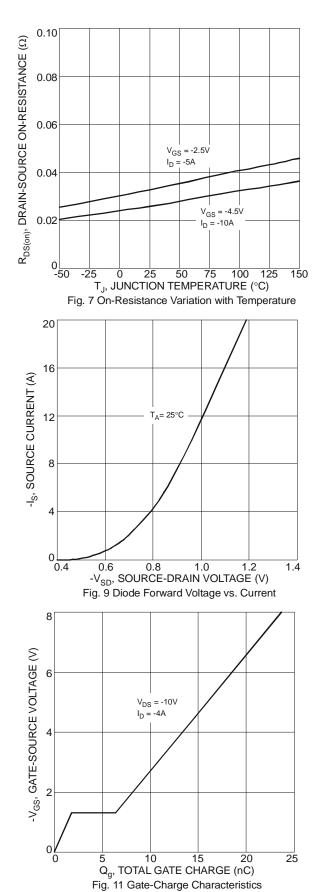
Notes:

- 5. Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
- $\hbox{6. Device mounted on 1"} \hbox{ x 1" FR-4 PCB with high coverage 2oz. Copper, single sided. } \\$
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.









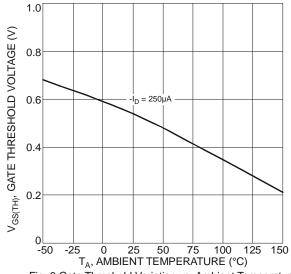
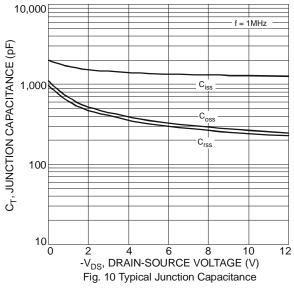
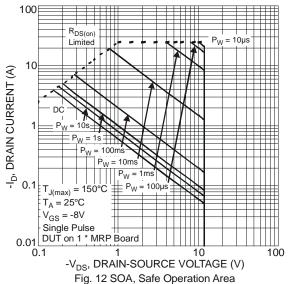
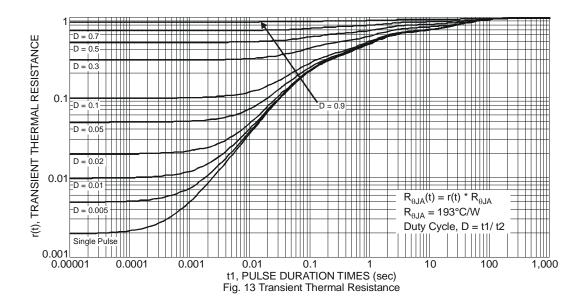


Fig. 8 Gate Threshold Variation vs. Ambient Temperature



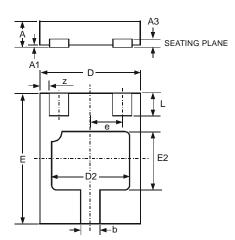






Package Outline Dimensions

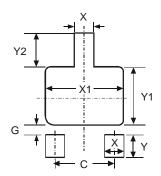
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| X2-DFN2015-3 | | | | | |
|----------------------|------|-------|-------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 1 | 0.40 | _ | | |
| A1 | 0 | 0.05 | 0.02 | | |
| А3 | 1 | _ | 0.13 | | |
| b | 0.20 | 0.30 | 0.25 | | |
| D | 1.45 | 1.575 | 1.50 | | |
| D2 | 1.00 | 1.20 | 1.10 | | |
| е | 1 | _ | 0.50 | | |
| Е | 1.95 | 2.075 | 2.00 | | |
| E2 | 0.70 | 0.90 | 0.80 | | |
| L | 0.25 | 0.35 | 0.30 | | |
| Z | 1 | _ | 0.125 | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 1.00 |
| G | 0.15 |
| Х | 0.31 |
| X1 | 1.30 |
| Y | 0.50 |
| Y1 | 1.00 |
| Y2 | 0.65 |



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